

SGM4896 1.15W Fully Differential Audio Power Amplifier

GENERAL DESCRIPTION

The SGM4896 is a fully differential audio power amplifier that is designed for portable communication device applications and demanding applications in mobile phones. It is capable of delivering 1.15W of continuous average power to an 8Ω BTL load with less than 1% distortion (THD+N) from a 5V battery voltage. It operates from 2.5V to 5.5V power supply.

The SGM4896 features a low-power consumption shutdown mode. To facilitate this, Shutdown may be enabled by logic low. Additionally, the SGM4896 features an internal thermal shutdown protection mechanism.

The SGM4896 contains advanced pop & click circuitry, a minimal count of external components and low-power shutdown mode. All these features make SGM4896 ideal for wireless handsets and other low voltage applications where minimal power consumption is a primary requirement.

The SGM4896 is available in Pb-free CSP-8 package. It operates over an ambient temperature range of -40°C to +85°C.

FEATURES

- Fully Differential Amplifier
- Excellent PSRR: Direct Connection to the Battery
- 1.15W to 8Ω BTL Load from 5V Supply at THD+N < 1% (TYP)
- 2.5V to 5.5V Operation
- Low Shutdown Current
- Shutdown Pin is Compatible with 1.8V Logic
- Improved Pop & Click Circuitry
- Thermal Overload Protection Circuitry
- No Output Coupling Capacitors, Bootstrap Capacitors Required
- External Gain Configuration Capability
- -40°C to +85°C Operating Temperature Range
- Pb-Free CSP-8 Package

APPLICATIONS

Portable Systems

Wireless Handsets

Mobile Phone

Handheld Computers

PDAs

GPS



PACKAGE/ORDERING INFORMATION

MODEL		ORDER NUMBER	PACKAGE DESCRIPTION	PACKAGE OPTION	MARKING INFORMATION	
	SGM4896	SGM4896YG/TR	CSP-8	Tape and Reel, 3000	4896YG	

ABSOLUTE MAXIMUM RATINGS

Supply Voltage	V
Input Voltage	3V
Storage Temperature Range65°C to +150°	'n
Junction Temperature	Ò,
Operating Temperature Range40°C to +85°	'n
Lead Temperature Range (Soldering 10 sec)	
260°	Ċ.
NOTES	

1. Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

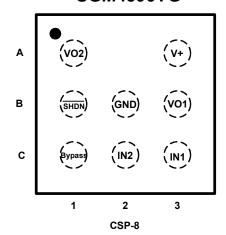
CAUTION

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

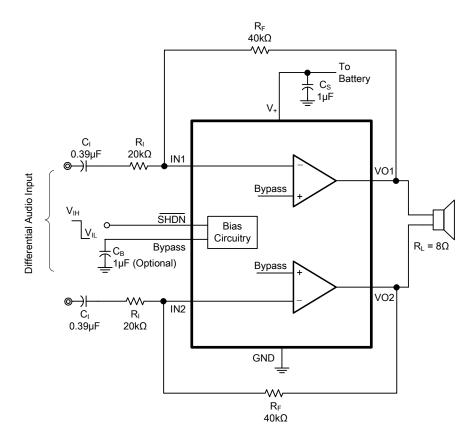
PIN CONFIGURATION (Top View)

SGM4896YG





TYPICAL APPLICATION



ELECTRICAL CHARACTERISTICS

Gain = 1 V/V, T_A = 25°C, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS		MIN 2.5	TYP	MAX 5.5	UNITS	
Supply Voltage	V ₊							
	I _{SD}	V _{SHDN} = 0V, I _{OUT} = 0mA	V ₊ = 5.0V		0.01	1	μΑ	
Shutdown Current			V+ = 3.6V		0.01	1		
			V ₊ = 2.5V		0.01	1		
	Vos	V _{SHDN} = 0V, I _{OUT} = 0mA	V ₊ = 5.0V	-15	0.86	15	mV	
Output Offset Voltage			V ₊ = 3.6V		0.75			
			V ₊ = 2.5V	-15	0.70	15		
	lα	V _{SHDN} = V ₊	V ₊ = 5.0V, No Load		4.88	6	mA	
			$V_{+} = 5.0V, 8\Omega \text{ Load}$		4.92	6.2		
Quiescent Power Supply Current			V ₊ = 3.6V, No Load		4.58			
Quiescent Fower Supply Current			$V_{+} = 3.6V, 8\Omega \text{ Load}$		4.62			
			V ₊ = 2.5V, No Load		4.36	5.5		
			$V_{+} = 2.5V, 8\Omega \text{ Load}$		4.38	5.6		
Shutdown Voltage Input High	V _{SDIH}			1.2			V	
Shutdown Voltage Input Low	V _{SDIL}					0.4	v	
	V _{OL}		V ₊ = 5.0V		0.46	0.9	V	
Low-Level Output Voltage		$V_{IN1} = V_{+}, R_{L} = 8\Omega,$	V+ = 3.6V		0.40			
		$V_{IN1} = V_+, R_L = 8\Omega,$ $V_{IN2} = GND, \text{ or } V_{IN2} = V_+,$	V+ = 2.5V		0.24	0.7		
	V _{OH}	V _{IN1} = GND	V ₊ = 5.0V	4.1	4.56		V	
High-Level Output Voltage			V ₊ = 3.6V		3.22			
			V+ = 2.5V	1.8	2.25			
	CMRR	V _{IC} = 0.5V to V ₊ - 0.8V	V+ = 5.0V		-77			
ommon Mode Rejection Ratio			V ₊ = 3.6V		-71		dB	
			V ₊ = 2.5V		-65			

Specifications subject to changes without notice.

ELECTRICAL CHARACTERISTICS

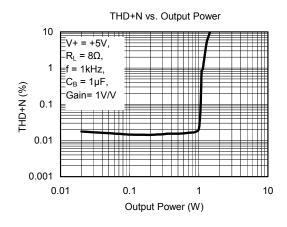
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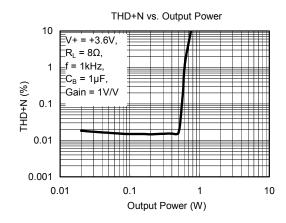
PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
	Po	$f = 1kHz$, $R_L = 8\Omega$, $THD+N < 1\%$	V ₊ = 5.0V		1.15		W
Output Pawar			V ₊ = 3.6V		0.6		
Output Power			V+ = 3.0V		0.4		
			V ₊ = 2.5V		0.28		
Total Harmonic Distortion + Noise	THD+N	$P_0 = 0.6$ Wrms, $f = 1$ kHz, $V_+ = 5$.	0V		0.02		%
	PSRR	V_{RIPPLE} = 200m V_{PP} , C_{I} = 0.39 μ F, C_{B} = 1 μ F, f = 217Hz, R_{L} = 8 Ω , 10 Ω Terminated Input	V ₊ = 5.0V		-73		- dB
			V+ = 3.6V		-71		
			V ₊ = 3.0V		-73		
Device County Dejection Detic			V ₊ = 2.5V		-72		
Power Supply Rejection Ratio		$V_{RIPPLE} = 200 m V_{PP}, \ C_I = 0.39 \mu F, \\ C_B = 1 \mu F, \ f = 1 k Hz, \ R_L = 8 \Omega, \\ 10 \Omega \ Terminated \ Input$	V ₊ = 5.0V		-73		
			V+ = 3.6V		-72		
			V ₊ = 3.0V		-74		
			V+ = 2.5V		-73		
Common Mode Rejection Ratio (1)	CMRR	$V_{+} = 5V, f = 217Hz,$ $V_{CM} = 200mV_{PP}, R_{L} = 8\Omega$	8Ω		-70		dB
	Twu		V+ = 5.0V		172		ms
Wake up Time			V ₊ = 3.6V		134		
Wake-up Time		- C _B = 1μF	V ₊ = 3.0V		115		
			V ₊ = 2.5V		102		
	Т _{SDT}		V ₊ = 5.0V		92		μs
Chutdown Time			V ₊ = 3.6V		52		
Shutdown Time			V+ = 3.0V		44		
			V ₊ = 2.5V		56		

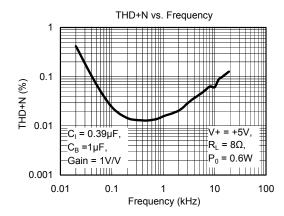
Note1: CMRR is affected by the matching between external gain-setting resistor ratios.

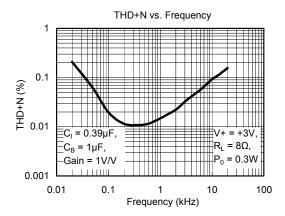
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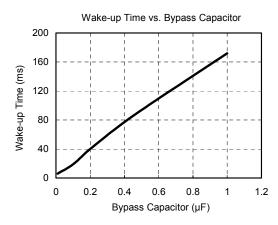
TYPICAL PERFORMANCE CHARACTERISTICS

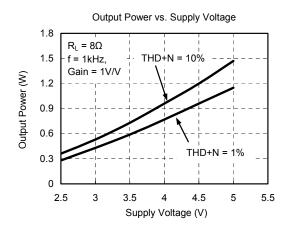




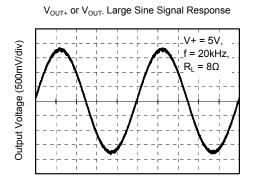




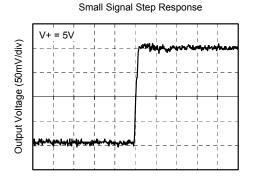




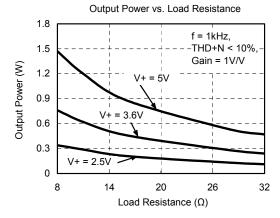
TYPICAL PERFORMANCE CHARACTERISTICS



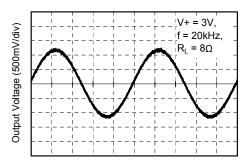




Time (2µs/div)

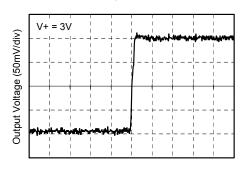


 $V_{\text{OUT+}}$ or $V_{\text{OUT-}}$ Large Sine Signal Response



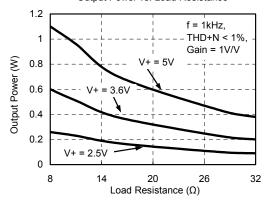
Time (10µs/div)

Small Signal Step Response

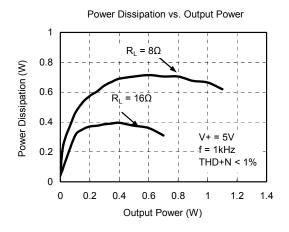


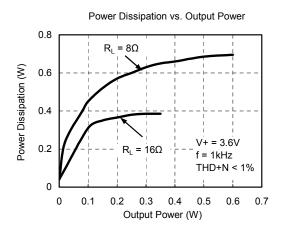
Time (2µs/div)

Output Power vs. Load Resistance



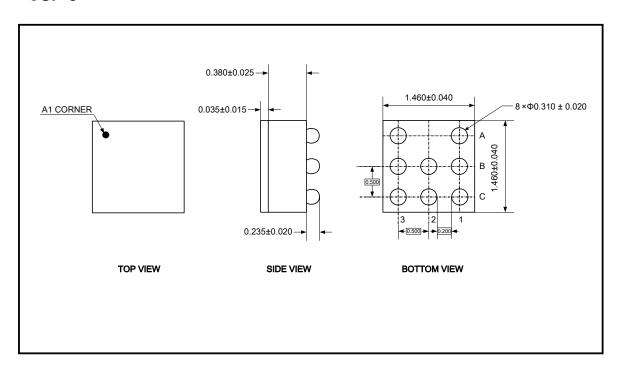
TYPICAL PERFORMANCE CHARACTERISTICS





PACKAGE OUTLINE DIMENSIONS

CSP-8



Note: All linear dimensions are in millimeters.

SGMICRO is dedicated to provide high quality and high performance analog IC products to customers. All SGMICRO products meet the highest industry standards with strict and comprehensive test and quality control systems to achieve world-class consistency and reliability.

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